



#### 40V DUAL PNP SMALL SIGNAL TRANSISTOR IN SOT563

## Features

- BV<sub>CEO</sub> > -40V
- I<sub>C</sub> = -200mA High Collector Current
- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

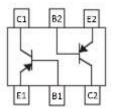


Top View

Bottom View

### **Mechanical Data**

- Case: SOT563
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish.
  Solderable per MIL-STD-202, Method 208 🕸
- Weight: 0.003 grams (Approximate)



Top View

### Ordering Information (Note 4)

Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
MMDT3906VC-7	Active	AEC-Q101	ARK	7	8	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

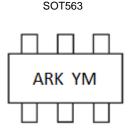
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**

Notes:



ARK = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: E = 2017) M or  $\overline{M}$  = Month (ex: 2 = February)

Date Code Key

Year	2017	201	8	2019	2020	2021	2022	2023	3 20	24	2025	2026	2027
Code	E	F		G	Н		J	K	l	-	М	Ν	0
Month	ו ו <b>ו</b>	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	1	2	3	4	5	6	7	8	9	0	N	D



## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-40	V
Emitter-Base Voltage	V <sub>EBO</sub>	-6	V
Collector Current	lc	-200	mA

# Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	150	mW
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	833	°C/W
Operating and Storage and Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## ESD Ratings (Note 6)

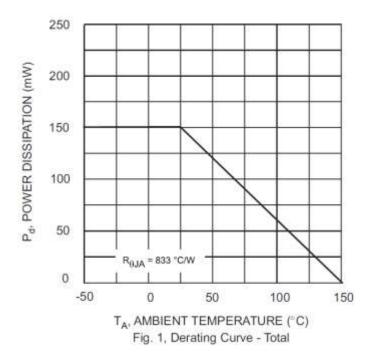
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# Thermal Characteristic and Derating Information





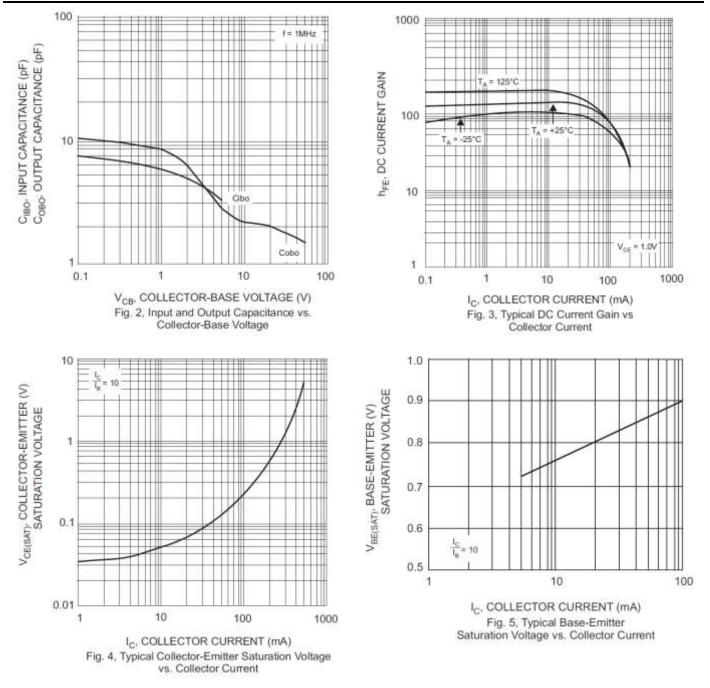
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS					·
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-40	—	V	$I_{C} = -100 \mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	-40	_	V	$I_{\rm C} = -1 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-6	_	V	$I_E = -100 \mu A, I_C = 0$
Collector Cut-Off Current	ICEX		-50	nA	VCE = -30V, $VEB(OFF) = -3V$
Base Cut-Off Current	I <sub>BL</sub>	_	-50	nA	VCE = -30V, $VEB(OFF) = -3V$
Emitter- Base Cut-Off Current	I <sub>EBO</sub>	_	-20	nA	$V_{EB} = -6V, I_{C} = 0$
ON CHARACTERISTICS (Note 7)			•		·
DC Current Gain	hFE	60 80 100 60 30	 300 	_	$\begin{split} I_{C} &= -100 \mu A, \ V_{CE} &= -1V \\ I_{C} &= -1mA, \ V_{CE} &= -1V \\ I_{C} &= -10mA, \ V_{CE} &= -1V \\ I_{C} &= -50mA, \ V_{CE} &= -1V \\ I_{C} &= -100mA, \ V_{CE} &= -1V \end{split}$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>		-0.25 -0.4	V	$I_{C} = -10mA$ , $I_{B} = -1mA$ $I_{C} = -50mA$ , $I_{B} = -5mA$
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	-0.65	-0.85 -0.95	V	$I_{C} = -10mA$ , $I_{B} = -1mA$ $I_{C} = -50mA$ , $I_{B} = -5mA$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	Сово		4.5	pF	$V_{CB} = -5V, f = 1MHz, I_E = 0$
Input Capacitance	CIBO		10	pF	$V_{EB} = -0.5V$ , f = 1MHz, I <sub>C</sub> = 0
Input Impedance	h <sub>IE</sub>	2	12	kΩ	
Voltage Feedback Ratio	h <sub>RE</sub>	0.1	10	x 10 <sup>-4</sup>	$V_{CE} = 10V, I_{C} = 1mA,$
Small Signal Current Gain	h <sub>FE</sub>	100	400	—	f = 1kHz
Output Admittance	h <sub>OE</sub>	3	60	μS	
Current Gain-Bandwidth Product	f⊤	250	—	MHz	$V_{CE} = -20V, I_C = -10mA, f = 100MHz$
Noise Figure	NF	_	4	dB	$V_{CE} = -5V, I_C = -100\mu A,$ $R_S = 1k\Omega, f = 1kHz$
SWITCHING CHARACTERISTICS					· · · ·
Delay Time	t <sub>D</sub>		35	ns	
Rise Time	t <sub>R</sub>		35	ns	$V_{CC} = -3V, I_{C} = -10mA,$
Storage Time	t <sub>S</sub>		200	ns	$-I_{B1} = I_{B2} = -1.0$ mA
Fall Time	t <sub>F</sub>		50	ns	]

Note: 7. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



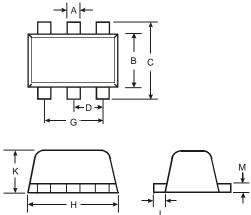
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





# Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

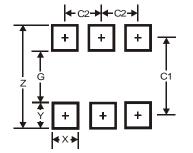


	SOT563						
Dim	Min	Max	Тур				
Α	0.15	0.30	0.20				
В	1.10	1.25	1.20				
С	1.55	1.70	1.60				
D	-	-	0.50				
G	0.90	1.10	1.00				
н	1.50	1.70	1.60				
к	0.55	0.60	0.60				
L	0.10	0.30	0.20				
М	0.10	0.18	0.11				
All	Dimens	sions in	mm				

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT563



Dimensions	SOT563
Z	2.2
G	1.2
Х	0.375
Y	0.5
C1	1.7
C2	0.5

SOT563



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